

FEATURES

- Silicon epitaxial planar diode
- Fast switching diode
- 500mW power dissipation
- This diode is also available in other case styles including: the DO-35 case with the type designation 1N4148, the SOD-323 case with the type designation 1N4148WS, the SOD-523 case with the type designation 1N4148WT.
- Component in accordance to RoHS 2015/863/EU

SOD-123FL



SOD-123



MECHANICAL DATA

- Case: SOD-123 plastic case
- Weight: Approx. 0.01 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified)

| | Symbols | Value | Units |
|--|-----------|-------------|------------------|
| DC Blocking Voltage | V_R | 75 | Volts |
| Non-Repetitive Peak Reverse Voltage | V_{RM} | 100 | Volts |
| Average rectified current, Half wave rectification with Resistive load at $T_A=25^\circ\text{C}$ and $f \geq 50\text{kHz}$ | I_{AV} | 150 | mA |
| Non-Repetitive Peak Forward Surge Current @ $t=1.0\text{s}$ | I_{FSM} | 500 | mA |
| Power dissipation at $T_A=25^\circ\text{C}$ | P_{tot} | 400 | mW |
| Junction temperature | T_J | 150 | $^\circ\text{C}$ |
| Storage temperature range | T_{STG} | -55 to +150 | $^\circ\text{C}$ |

ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified)

| | Symbol | Min. | Typ. | Max. | Units |
|---|-----------------|------|------|------|--------------------|
| Forward voltage at $I_F=10\text{mA}$ | V_F | | | 1 | Volts |
| Leakage current at $V_R=20\text{V}$ at $V_R=75\text{V}$ at $V_R=20\text{V}, T_J=150^\circ\text{C}$ | I_R | | | 25 | nA |
| | I_R | | | 5 | μA |
| | I_R | | | 50 | μA |
| Junction capacitance at $V_R=V_F=0\text{V}$ | C_J | | | 4 | pF |
| Voltage rise when switching on tested with 50mA pulse $t_p=0.1\mu\text{s}$, Rise time $<30\mu\text{s}$, $f_p=5$ to 100kHz | V_{fr} | | | 2.5 | Volts |
| Reverse recovery time from $I_F=10\text{mA}$ to $I_R=1\text{mA}$, $V_R=6\text{V}$, $R_L=100\Omega$ | t_{rr} | | | 4 | ns |
| Thermal resistance junction to ambient | $R_{\theta JA}$ | | 312 | | $^\circ\text{C/W}$ |
| Rectification efficiency at $f=100\text{MHz}$, $V_{RF}=2\text{V}$ | η | 0.45 | | | |

RATINGS AND CHARACTERISTIC CURVES 1N4148W

FIG 1-FORWARD CHARACTERISTICS

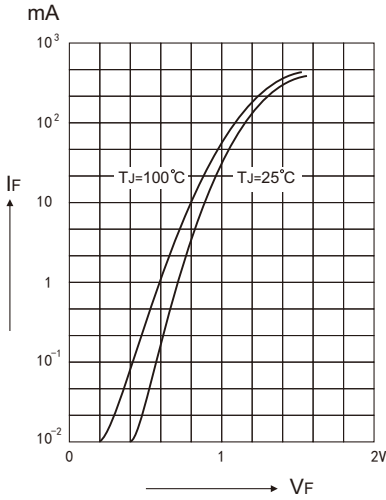


FIG 2: DYNAMIC FORWARD RESISTANCE VERSUS FORWARD CURRENT

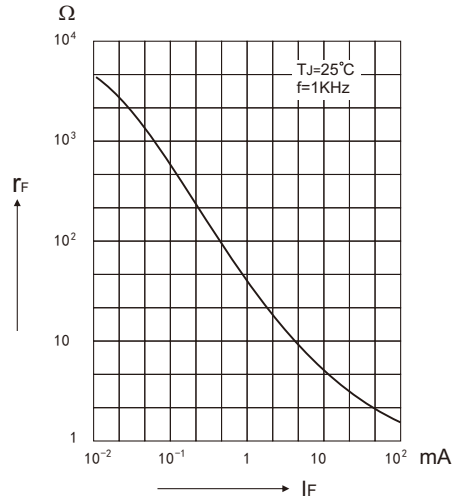


FIG 3-ADMISSIBLE POWER DISSIPATION VERSUS AMBIENT TEMPERATURE

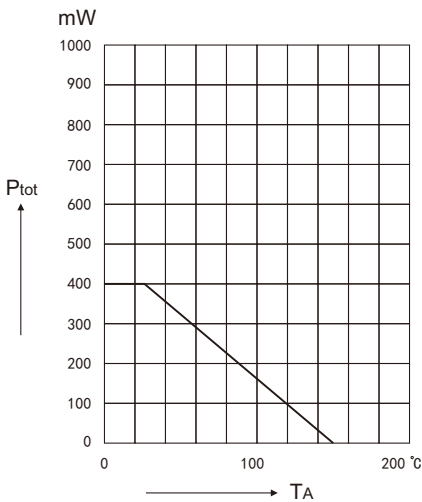
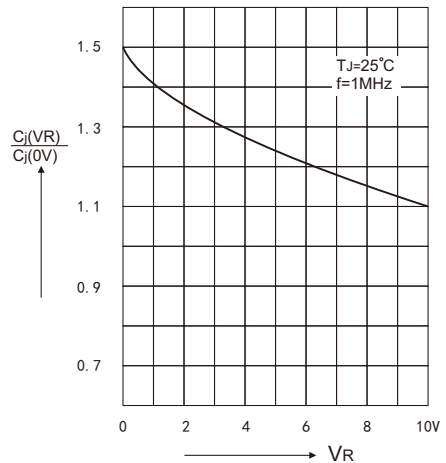


FIG. 4-RELATIVE CAPACITANCE VERSUS VOLTAGE



RATINGS AND CHARACTERISTIC CURVES 1N4148W

FIG.5 RECTIFICATION EFFICIENCY MEASUREMENT CIRCUIT

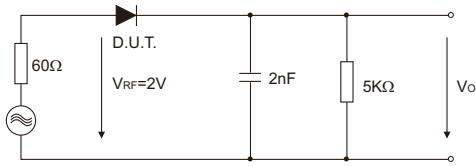


FIG 6: LEAKAGE CURRENT VERSUS JUNCTION TEMPERATURE

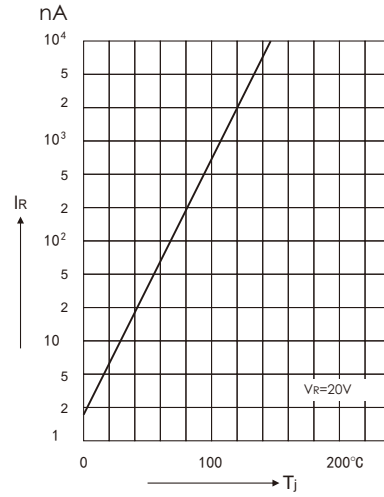
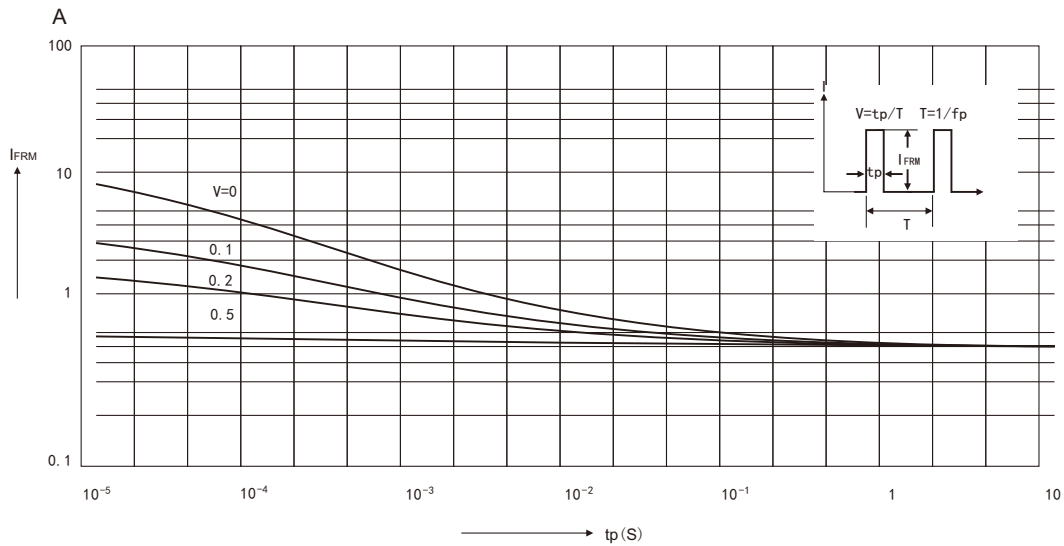


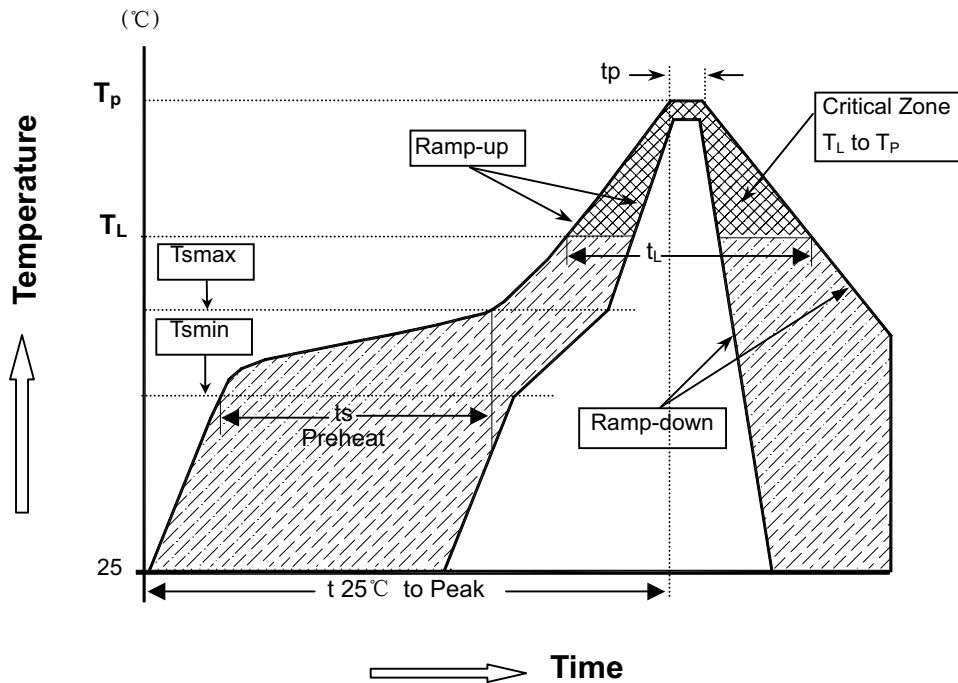
FIG 7: ADMISSIBLE REPETITIVE PEAK FORWARD CURRENT VERSUS PULSE DURATION



RATINGS AND CHARACTERISTIC CURVES 1N4148W

1. Recommended of reflow soldering condition.

| Profile Feature | Pb-Free Assembly |
|--|----------------------------------|
| Average ramp-up rate ($T_{s_{max}}$ to T_P) | 3°C/second max. |
| Preheat Temperature Min ($T_{s_{min}}$) Temperature Max ($T_{s_{max}}$) Time (min to max) (t_s) | 150°C 200°C 60-180 seconds |
| Time maintained above: Temperature (T_L) Time (t_L) | 217°C 60-150 seconds |
| Peak Temperature (T_P) | 260±0°C |
| Time within 5°C of actual Peak Temperature (t_p) | 20-40 seconds |
| Ramp-down Rate | 6°C/second max. |
| Time 25°C to Peak Temperature | 8 minutes max. |



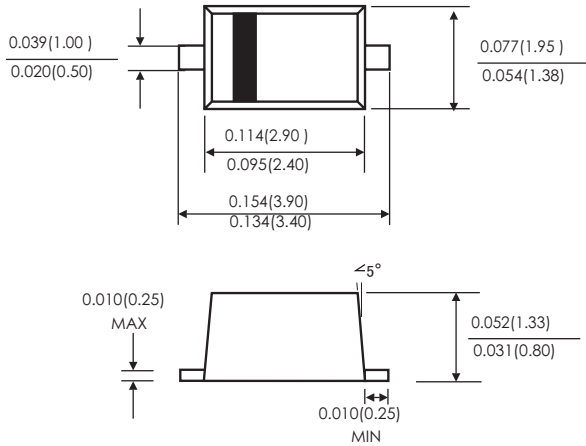
2. Condition of hand Soldering

Temperature: 370 °C max.

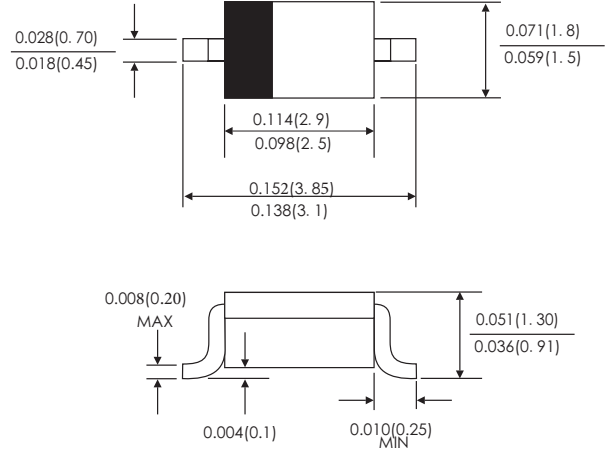
Time: 3sec. max.

RATINGS AND CHARACTERISTIC CURVES 1N4148W

SOD-123FL

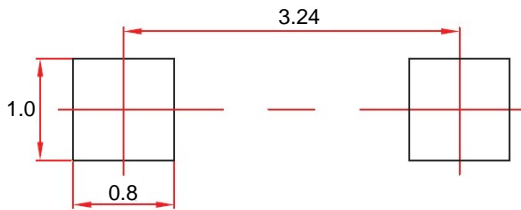


SOD-123



Dimensions in inches and (millimeters)

Suggested Pad Layout



Note:

1. Dimension: mm
2. General tolerance: ± 0.05 mm
3. The pad layout is for reference purpose only

Friendship Reminder

■ JiNan JingHeng (hereinafter referred to as JH) reserves the right to make changes to this document and its products and specifications at anytime without notice.

济南晶恒（以下简称 JH）保留未经通知，变更本文件和与本文件相关的产品及规格的权利。

■ Customers should obtain and confirm the latest product information and specifications before final design, purchase or use.

使用方应在使用、采购本产品之前获取并确认产品信息和规格书的最新版本。

■ JH makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does JH assume any liability for application assistance or customer product design.

JH 对其产品用于某特定用途的适用性，既不做任何保证、说明或担保，也不承担任何应用协助或使用方设计的法定责任。

■ JH does not warrant or accept any liability with products which are purchased or used for any unintended or unauthorized application.

JH 不保证或承担任何责任，其产品被采购使用于任何非预期或授权的应用，

■ No license is granted by implication or otherwise under any intellectual property rights of JH.

此规格书属于 JH 的知识产权,没有经过我司授权不得抄袭。

■ JH's products are not authorized for use as critical components in life support devices or systems without express written approval of JH.

没有 JH 的书面授权，JH 的产品不能在生命支撑设备或系统里作为关键零件使用。